



DMP2101UCB9

Product Summary

BV _{D1D2}	R _{D1D2(ON)} Typ.	I _{D1D2} T _A = +25°C
-20V	$63m\Omega@V_{GS} = -4.5V$	-3.2A

Description

This new generation MOSFET is designed to minimize the on-state resistance $(R_{D1D2(ON)})$ and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Battery Management
- Load Switch
- Battery Protection



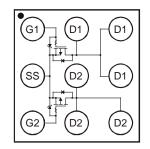
DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- LD-MOS Technology with the Lowest Figure of Merit:
 - R_{D1D2(ON)} = 63mΩ to Minimize On-State Losses
 - Q_g = 3.2nC for Ultra-Fast Switching
- V_{GS(TH)} = -0.74V Typ. for a Low Turn-On Potential
- CSP with Footprint 1.5mm × 1.5mm
- Height = 0.62mm for Low Profile
- Gate ESD Protection <HBM Class 3A>
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-WLB1515-9 (Type E)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal: Finish SnAgCu. Solderable per MIL-STD-202 Method 208 (ef)
- Terminal Connections: See Diagram Below
- Weight: 0.0018 grams (Approximate)



Top View

Ordering Information (Note 4)

	Part Number	Case	Packaging			
	DMP2101UCB9-7	U-WLB1515-9 (Type E)	3000/Tape & Reel			
Notes:	1 No purposely added lead. Fully FU Directive 2002/95/FC (BoHS), 2011/65/FU (BoHS 2) & 2015/863/FU (BoHS 3) compliant					

No purposely added lead. Fully to blective 2002/30/E0 (Korlo), 20 moneto (Korlo 2) a 20 moneto (Korlo 2) active compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

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	6D	
	YΜ	

6D = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key	
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Year	201	5	2016		2017		2018			2020	2	2021
Code	С		D		E		F	G		Н		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-to-Drain Voltage		V _{D1D2}	-20	V	
Gate-to-Source Voltage		V _{GS}	-6	V	
Continuous Drain Current (Note 5) V_{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	I _{D1D2}	-2.2 -1.7	А
Continuous Drain Current (Note 6) V_{GS} = -4.5V	I _{D1D2}	-3.2 -2.5	А		
Continuous Source Pin Current (Note 6)			ls	-1.6	A
Pulsed Source Pin Current (Pulse Duration 10µs, I	Duty Cycle	I _{SM}	-25	A	
Pulsed Drain Current (Pulse Duration 10µs, Duty C	Cycle ≤ 1%)	IDM	-25	A	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	0.74	W
Total Power Dissipation (Note 6)	PD	1.56	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	170	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	81	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

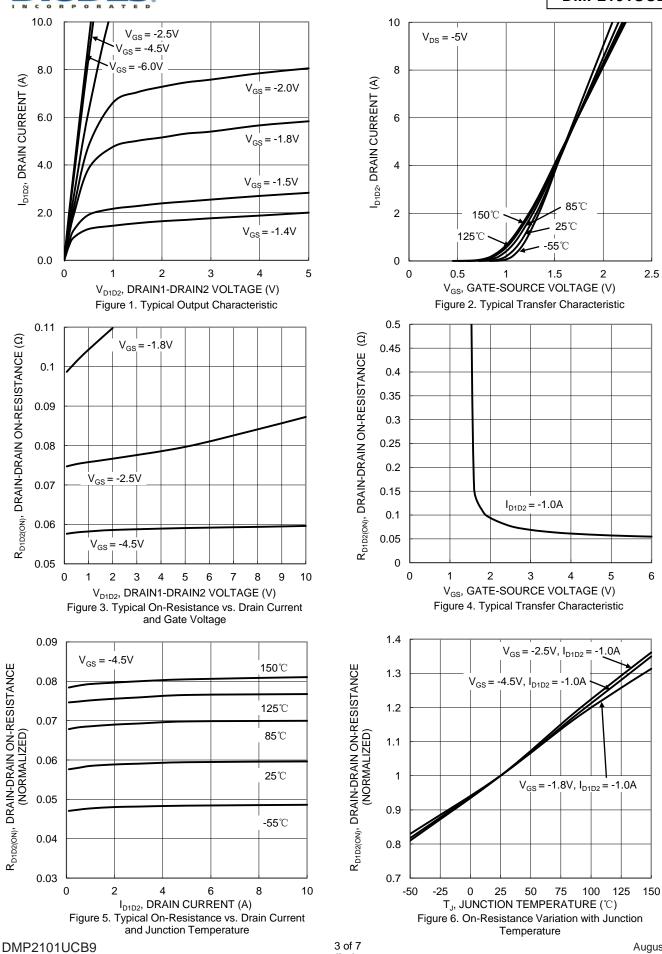
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	· ·					-
Drain-to-Drain Breakdown Voltage	BV _{D1D2}	-20	—	_	V	$V_{GS} = 0V, I_{D1D2} = -250 \mu A$
Zero Gate Voltage Drain Current @T _C = +25°C	I _{DDS}	_	_	-1	μA	$V_{D1D2} = -16V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	—	-100	nA	$V_{GS} = -6V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	· ·					-
Gate Threshold Voltage	V _{GS(TH)}	-0.4	-0.74	-0.9	V	$V_{D1D2} = V_{GS}, I_{DS} = -250 \mu A$
		_	63	100		V _{GS} = -4.5V, I _{D1D2} = -1A
Static Drain-to-Drain On-Resistance	R _{D1D2(ON)}	—	72	130	mΩ	V _{GS} = -2.5V, I _{D1D2} = -1A
		—	87	175		V _{GS} = -1.8V, I _{D1D2} = -1A
DIODE CHARACTERISTICS	• • • • •		•	•	•	·
Diode Forward Voltage (Note 6)	V _{SD}	_	-0.7	-1	V	$V_{GS} = 0V, I_{D1D2} = -1A$
Reverse Recovery Charge	Q _{RR}	_	4.1	_	nC	V _{D1D2} = -9.5V, I _F = -1A,
Reverse Recovery Time	t _{RR}	—	10.5	—	ns	di/dt = 200A/µs
DYNAMIC CHARACTERISTICS (Note 8)	• • • • •		•	•	•	·
Input Capacitance	C _{iss}	_	392	588	pF	
Output Capacitance	Coss	_	183	274	pF	$V_{D1D2} = -10V, V_{GS} = 0V,$ = f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	8.4	12.6	pF	
Series Gate Resistance	R _g	_	5.2	10	Ω	V _{GS} = 0V, V _{D1D2} = 0V, f = 1.0MHz
Total Gate Charge (-4.5V)	Qg		3.2	4.8	nC	
Gate-Source Charge	Q _{gs}		0.3	_	nC	$V_{GS} = -4.5V, V_{D1D2} = -10V,$
Gate-Drain Charge	Q _{gd}	—	0.6	_	nC	I _{D1D2} = -1A
Gate Charge at V _{th}	Q _{g(th)}	_	0.18		nC	
Turn-On Delay Time	t _{D(ON)}	_	3.6	7	ns	
Turn-On Rise Time	t _R	_	5.3	_	ns	V _{D1D2} = -10V, V _{GS} = -4.5V,
Turn-Off Delay Time	t _{D(OFF)}	_	40	80	ns	$I_{D1D2} = -1A, R_G = 30\Omega$
Turn-Off Fall Time	tF	—	20		ns	7

Notes:

Device mounted on FR-4 PCB with minimum recommended pad layout.
Device mounted on FR-4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



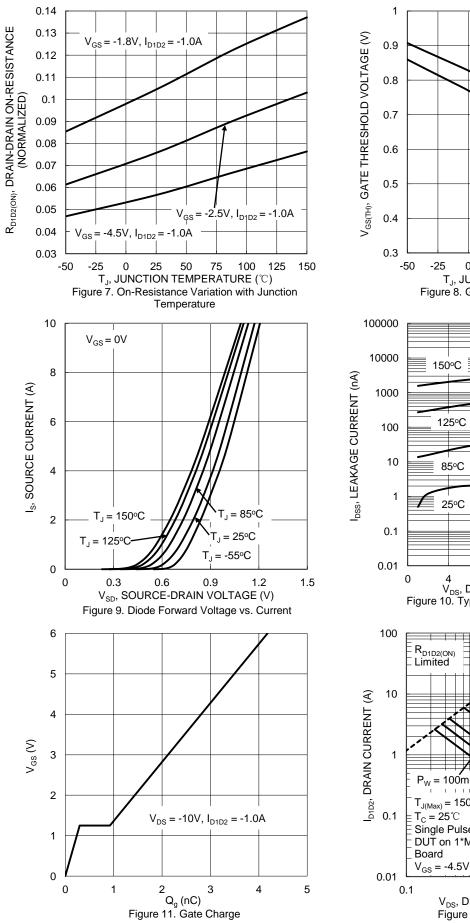
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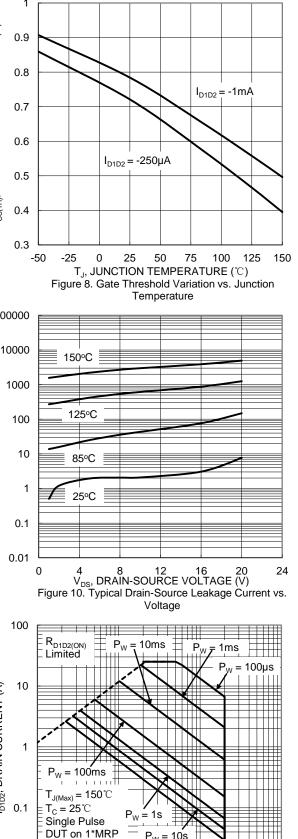


Document number: DS40685 Rev. 4 - 2



DMP2101UCB9





10s

V_{DS}, DRAIN-SOURCE VOLTAGE (V)

Figure 12. SOA, Safe Operation Area

DC

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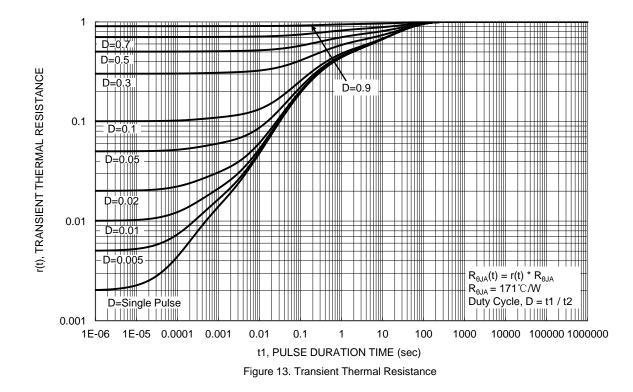
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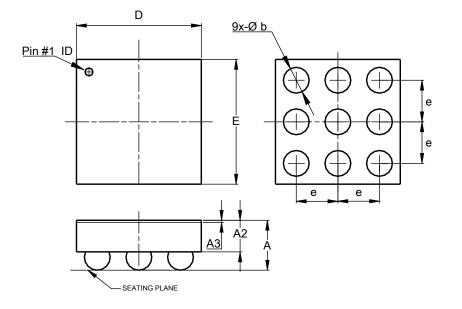




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1515-9 (Type E)

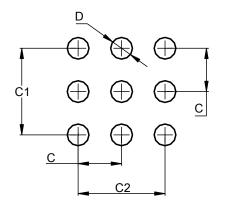


U-WLB1515-9 (Type E)								
Dim	Min	Max	Тур					
Α		0.62						
A2		0.36	0.36					
A3	0.020	0.030	0.025					
b	0.27	0.37	0.32					
D	1.47	1.51	1.49					
E	1.47	1.51	1.49					
е			0.50					
All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1515-9 (Type E)



Dimensions	Value (in mm)			
С	0.50			
C1	1.00			
C2	1.00			
D	0.25			



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